IRFP044N MOSFET

Charactiristics IRFP044N MOSFET transistor

• Type: n-channel

• Drain-to-Source Breakdown Voltage: 55 V

• Gate-to-Source Voltage, max: ±20 V

• Drain-Source On-State Resistance, max: 20.000 Ohm

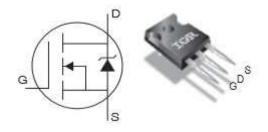
• Continuous Drain Current: 49 A

• Total Gate Charge: 40.7 nC

Power Dissipation: 100 W

• Package: TO-247AC

Pin Configuration (Pinout)



IRFP044N Replacement and Equivalent transistors

You can replace IRFP044N with IRFP044N (/mosfets/irfp048n), IRFP054N (/mosfets/irfp054n), IRFP064N (/mosfets/irfp064n), IRFP1405 (/mosfets/irfp1405), IRFP2907 (/mosfets/irfp2907z), IRFP2907Z (/mosfets/irfp2907z), IRFP3077 (/mosfets/irfp3077), IRFP3206 (/mosfets/irfp3206), IRFP3306 (/mosfets/irfp3306), IRFP4110 (/mosfets/irfp4110), IRFP4310Z (/mosfets/irfp4310z), IRFP4321 (/mosfets/irfp4368), IRFP4368 (/mosfets/irfp4368), IRFP4368 (/mosfets/irfp4568), IRFP4668 (/mosfets/irfp4710), IRFP4768 (/mosfets/irfp4768)